TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HCT32AP, TC74HCT32AF, TC74HCT32AFN

QUAD 2-INPUT OR GATE

The TC74HCT32A is a high speed CMOS 2-INPUT OR GATE fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

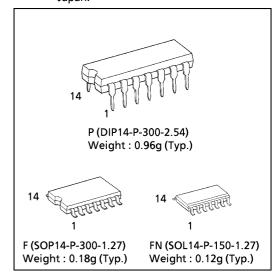
FEATURES:

- High Speed······ t_{pd} = 12ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ············ $I_{CC} = 1\mu A(Max.)$ at Ta = 25°C
- Compatible with TTL outputs \cdots $V_{IH} = 2V$ (Min.)

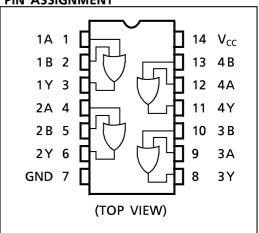
 $V_{1L} = 0.8V \text{ (Max.)}$

- Wide interfacing ability LSTTL, NMOS, CMOS
- Output Drive Capability10 LSTTL Loads
- Symmetrical Output Impedance | I_{OH} | = I_{OL} = 4mA(Min.)
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with 74LS32

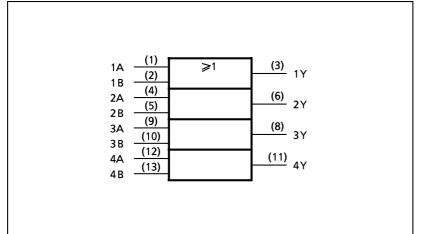
(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE

Α	В	Υ
Н	Н	Н
L	Н	Н
Н	L	Н
L	L	L

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{cc}	− 0.5~7	V
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} / Ground Current	I _{cc}	± 50	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

^{*500}mW in the range of Ta = -40° C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	4.5~5.5	V
Input Voltage	V _{IN}	0~V _{cc}	V
Output Voltage	V _{OUT}	0~V _{cc}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	t _r , t _f	0~500	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER SYM	SYMBOL	L TEST CONDITION		V _{cc}	7	Ta = 25°C			Ta = −40~85°C	
FARAIVIETER STIVIB		. TEST CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	V _{IH}			4.5 { 5.5	2.0	_	_	2.0	_	V
Low - Level Input Voltage	VIL			4.5 \$ 5.5	_	_	0.8	1	0.8	٧
High - Level Output Voltage	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	V	
		$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	V	
Low - Level	V _{OL}	V _{1 N} =	$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	-	0.1	<
Output Voltage	V_{IH} or V_{IL}	$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	V	
Input Leakage Current	I _{I N}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	± 0.1	_	± 1.0	
Quiescent Supply Current I _C	I _{cc}	$V_{1N} = V_{CC}$ or GND		5.5	_	_	1.0	-	10.0	μA
	I _C	PER INPUT:V _{IN} OTHER INPUT	ı = 0.5V or 2.4V :V _{CC} or GND	5.5	_	_	2.0	_	2.9	mA

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AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, $Ta = 25^{\circ}C$, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t _{TLH} t _{THL}		_	6	12	ns
Propagation Delay Time	t _{pLH} t _{pHL}		_	10	16	113

AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°0		<u> </u>	Ta = −40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	CIVIII
Output Transition Time	t _{TLH}		4.5	_	8	15	_	19	
	t _{THL}		5.5	_	7	13	_	16	ns
Propagation Delay Time	t _{pLH}		4.5	_	13	20	_	25	113
	t _{pHL}		5.5	_	11	18	_	23	
Input Capacitance	C _{IN}			_	5	10	_	10	рF
Power Dissipation Capacitance	C _{PD} (1)			_	23	_	_	_	þΓ

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

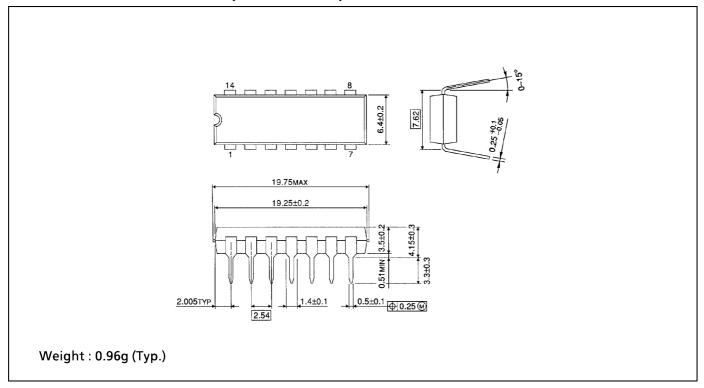
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4$ (per Gate)

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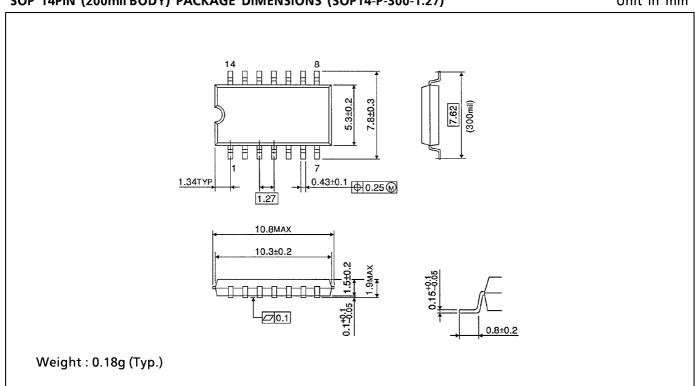
DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

Unit in mm



SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

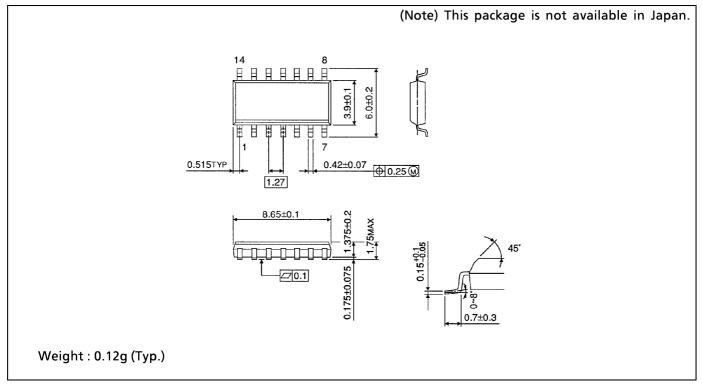
Unit in mm



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SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



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